

CW Quantum Cascade Laser L12007-1392H-C

■ Features

■ Emission wavelength: 7.18 µm (Typ.)

Output power: 20 mW (Min.)Threshold current: 1.0 A (Max.)

■ Applications

● Trace gas analysis (SO₃)



■ Outline

Quantum Cascade Lasers, using structures of SPC (Single Phonon-Continuum) depopulation and DFB (Distributed Feedback), emit CW (Continuous Wave) mid-IR laser under room temperature.

By controlling the chip's operating temperature through the Peltier element installed in the HHL package, it is possible to tune the emission wavelength without mode hopping while keeping longitudinal single mode operation.

■ Absolute and characteristics

 $T_{op(qcl)}$) = +20 °C, unless otherwise specified.

Parameter	Symbol	Ratings	Unit
Forward current *1	lf	This product has individual difference.	Α
Forward voltage *1	Vf	Confirm data sheet attached to a product *2	V
Reverse voltage *1	Vr	0.0	V
Change speed of forward current *3	_	5	mA/s
TEC current (cooling mode) *4	I.	+3.7	Α
TEC current (heating mode) *4	Ic	-1.5	Α
TEC voltage	V _C	±13.0	V
Operating temperature (case) *5*6	T _{op(c)}	+10 to +60	O°
Operating temperature (QCL) *7	T _{op(qcl)}	0 to +55	°C
Change speed of operating temperature *8	_	10	°C/min
Storage temperature *5	T _{stg}	-20 to +65	°C

^{*1} Confirm data sheet attached to a product. Sensitive to electrical surges and instability. Reverse current/voltage cause damage in laser specifications and out of warranty.

■ Specifications (laser)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Operating temperature (QCL) *1	T _{op(qcl)}	K *2=1392 cm ⁻¹	+10	_	+50	°C
Spectral linewidth *3	ΔKL	K *2=1392 cm ⁻¹	_	_	0.2 *4	cm ⁻¹
Wavenumber tuning range *5	ΔKT	K *2=1392 cm-1	±1.0	_	_	cm ⁻¹
Radiant power	Фе	K *2=1392 cm ⁻¹	20	_		mW
Threshold current	I _{th}	T _{op(qcl)=+20 °C}	_	_	1.0	Α
Side mode suppression ratio	SMSR	Top(qcl)=+20 °C	25 *4	_	_	dB

^{*1} This product is able to emit the target wavenumber at a certain Top(qcl) within the specified temperature range.

^{*2} Necessary specifications of power supply: $I_f \ge 1.3 \text{ A}$, $V_f \ge 16 \text{ V}$.

^{*3} Speed when changing the forward currrent (If).

^{*4} Even if TEC current (I_c) is below the absolute maximum, insufficient heat dissipation from this product may cause damage in laser and TEC specifications and out of warranty. Especially there are possibilities of damage, degradation and less reliability when TEC is operated in heating mode since heated-up side (laser chip) is thermally isolated from case of package and ambience. Refer to schematic configuration in 3-2-4.

^{*5} Avoid water condensation.

^{*6} Temperatures of case (body) of HHL-package.

^{*7} Temperatures of QC-laser when operated; should be monitored by the built-in thermistor for Top(qcl).

^{*8} Speed when changing the operation temperature (Top(qcl)) controlled by the built-in TEC.

^{*2} K: Emission wavenumber (cm⁻¹).

^{*3} WHM

^{*4} These values are limited by resolution and singnal-to-noise ratio of instrument when tested.

^{*5} Continuously wavenumber scan range; Center of the tunability range is the emission wavenumber (K).

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■TEC

Parameter	Symbol	Condition	Specification	Unit
Maximum temperature difference	ΔT_{max}	$T_h=27$ °C, in N ₂ , Q _C =0, Ic=+3.7 A	>40	°C
Maximum heat pumping capacity	Qcmax	$T_{h}= 27 ^{\circ}C$, in N ₂ , I _C =+3.7 A, $\Delta T=0$	>18	W
AC resistance	ACR	T _h =27 °C, 1 kHz	2.5 ± 0.3	Ω

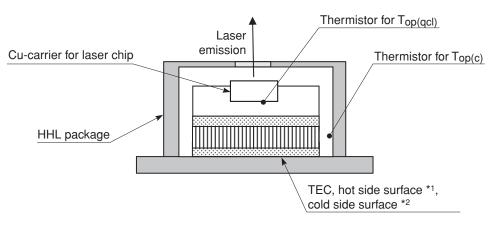
^{*} ΔT : Temperature difference

■ Thermistor

Parameter	Symbol	Condition	Specification	Unit
Resistance	R ₂₅	25 °C	10 kΩ ± 2.5 %	_
Beta value	В	0 °C / 100 °C	3450 K	_

^{*} Same specifications for both thermisters of Top(qcl) and Top(c).

Figure 1: Thermistor configurations (schematic)



^{*1} when TEC is operated in cooling mode.

Q_c: Heat pumping capacity

I_c: TEC current

Th: Temperature of TEC's hot side surface (TEC: cooling mode)

^{*2} when TEC is operated in heating mode.

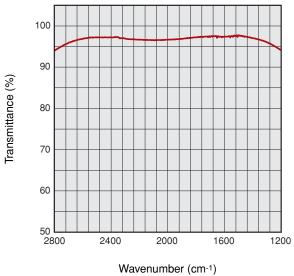
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■ Window of HHL package

Parameter		Specification	
Material		ZnSe, Plano-Plano	_
Dimension	Clear aperture *1	φ4.4	mm
Dimension	Thickness	0.7	mm
	Coating	BBAR, both surface	_
Coating	Bandwidth	2500 to 1250	cm ⁻¹
	Transmittance *2	>96	%

^{*1} Mechanical aperture of HHL package.

Figure 2: Typical transmittance curve of the window

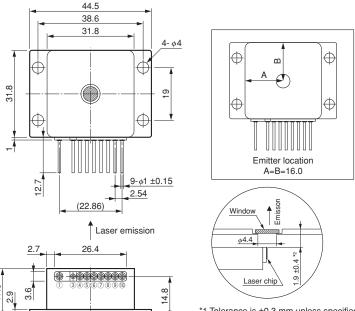


■ Necessary specifications of power supply for the laser (QCL)

Parameter	Specification	
Output current	≥1.3	Α
Output voltage	≥16	V
Function	Surge protect	_
Function	Constant current control	_

^{*2} Average in the bandwidth.

Figure 3: Dimensional outline and pin connection (unit: mm)



^{*1} Tolerance is ±0.3 mm unless specified.

^{*2} Edge of QCL chip and outside of the package.

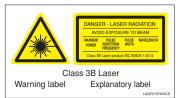
Pin No. *3	Function	Pin No. *3	Function
1	TEC cathode (-)	7	QCL cathode (-)
3	N.C.	8	Thermistor, (Top(c))
4	QCL anode (+)	9	Thermistor, (Top(c))
(5)	Thermistor, (Top(qcl))	10	TEC anode (+)
6	Thermistor, (Top(qcl))	_	_

^{*3} Pin of ③ is electrically connected to the case; package body. Other all pins are floating to the case.

Warning (Class 3B Laser) Invisible laser radiation: Avoid exposure to beam

●The laser radiation emitted from this product is an invisible laser beam that cannot be seen by the human eye. This product falls within "Class 3B Laser" according to IEC 60825-1 laser product classification.

Always comply with IEC 60825-1 safety standards when using this product.



•Information described in this material current as of October 2023. Specifications are subject to change without notice.

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